

# 2729-170

### 170 Watts, 38 Volts, 100μs, 10% Radar 2700-2900 MHz

#### **GENERAL DESCRIPTION**

The 2729-170 is an internally matched, COMMON BASE bipolar transistor capable of providing 170 Watts of pulsed RF output power at 100µs pulse width, 10% duty factor across the 2700 to 2900 MHz band. The transistor prematch and test fixture has been optimized through the use of Pulsed Automated Load Pull. This hermetically solder-sealed transistor is specifically designed for S-band radar applications. It utilizes gold metallization and emitter ballasting to provide high reliability and supreme ruggedness.

### CASE OUTLINE 55KS-1 Common Base

#### ABSOLUTE MAXIMUM RATINGS

**Maximum Power Dissipation** 

Device Dissipation @ 25°C<sup>1</sup> 570 W

**Maximum Voltage and Current** 

 $\begin{array}{lll} \mbox{Collector to Base Voltage } (\mbox{BV}_{ces}) & \mbox{65 V} \\ \mbox{Emitter to Base Voltage } (\mbox{BV}_{ebo}) & \mbox{3.0 V} \\ \mbox{Collector Current } (\mbox{I}_c) & \mbox{17 A} \\ \end{array}$ 

**Maximum Temperatures** 

 $\begin{array}{lll} \mbox{Storage Temperature} & -65 \mbox{ to } +200 \mbox{ °C} \\ \mbox{Operating Junction Temperature} & +200 \mbox{ °C} \\ \end{array}$ 



#### **ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P <sub>out</sub>	Power Output	F=2700-2900 MHz	170			W
P <sub>in</sub>	Power Input	$V_{cc} = 38 \text{ Volts}$			25.7	W
$P_{g}$	Power Gain	Pulse Width = $100 \mu s$	8.2	8.6		dB
$\eta_{\rm c}$	Collector Efficiency	Duty Factor = 10%	52	60		%
VSWR	Load Mismatch Tolerance <sup>1</sup>	$F = 2900 \text{ MHz}, P_0 = 170 \text{ W}$			2:1	

#### **FUNCTIONAL CHARACTERISTICS @ 25°C**

$\mathrm{BV}_{\mathrm{ebo}}$	Emitter to Base Breakdown	Ie = 30  mA	3.0			V
Iebo	Emitter to Base Leakage	Veb = 1.5 V			2	mA
$BV_{ces}$	Collector to Emitter Breakdown	Ic = 120  mA	56	65		V
Ices	Collector to Emitter Leakage	Vce = 36 V			7	mA
$h_{FE}$	DC – Current Gain	Vce = 5V, $Ic = 600  mA$	18	50		
θjc <sup>1</sup>	Thermal Resistance				0.30	°C/W

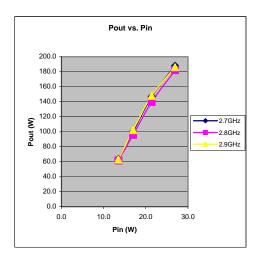
NOTE: 1. At rated output power and pulse conditions

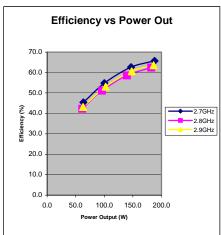
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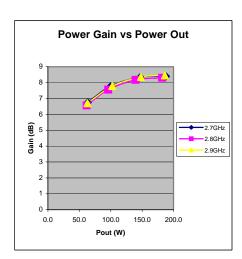


Vcc = 38 Volts, Pulse Width =  $100\mu$ s, Duty = 10% G2754-2,

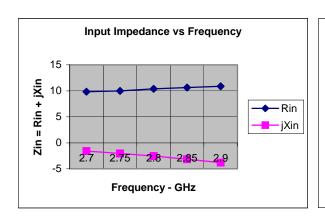
Product is in characterization, additional curves will be inserted at the conclusion.

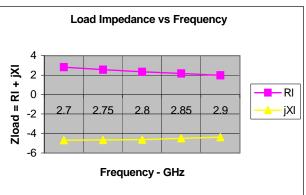






Input and Load Impedance

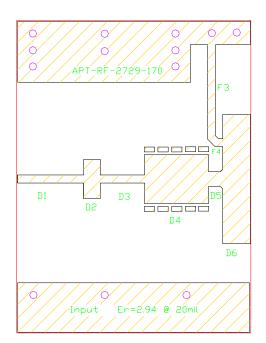


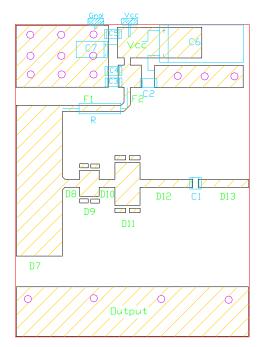


Note:  $Z_{\it in}$  is looking into the transistor input,  $Z_{\it Load}$  is looking into the Output Circuit.

### 2729-170

## Broadband Test Circuit -





Destination	W (Mil)	L (Mil)
F1	51	115
F2	51	395
F3	51	630
F4	51	50
D1	51	424
D2	250	107
D3	51	284
D4	314	410
D5	96	91
D6	827	177
D7	965	295
D8	51	110
D9	166	125
D10	51	100

Destination	W (Mil)	L (Mil)		
D11	274	160		
D12	51	336		
D13	51	324		
Duroid 6002, 20Mil, 1Oz Cu				
List of component				
Destination	Value	Size		
C1	10pF	Α		
C2	1000pF	В		
C3	10000pF	В		
C4	10000pF	В		
C5	10000pF	В		
C6	2200uF	Electrolytic		
C7	47uF	Electrolytic		
R	2.5 ohms (may needed)	Fix		

